Technical Data Sheet



DPDT Ramses SMA2.9 40GHz Latching 12Vdc TTL Diodes Pins Terminals with bracket

With bracket

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RF CHARACTERISTICS

Frequency range : 0 - 40 GHz Impedance : 50 Ohms

Frequency (GHz)	DC - 6	6 - 12.4	12.4 - 18	18 - 26.5	26.5 - 40
VSWR max	1.30	1.40	1.50	1.70	1.90
Insertion loss max	0.30 dB	0.40 dB	0.50 dB	0.70 dB	0.80 dB
Isolation min	70 dB	60 dB	60 dB	55 dB	50 dB
Average power (*)	80 W	60 W	50 W	20 W	10 W

ELECTRICAL CHARACTERISTICS

Actuator : LATCHING
Nominal current ** : 320 mA

Actuator voltage (Vcc) : 12V (10.2 to 13V)

Terminals : solder pins (250°C max. / 30 sec.)
TTL inputs (E) - High level : 2.2 to 5.5 V / 800µA at 5.5 V

- Low level : 0 to 0.8 V / 20µA at 0.8 V

MECHANICAL CHARACTERISTICS

Connectors : SMA 2.9 female per MIL-C 39012

Life : 2.5 million cycles

Switching Time*** : <15 ms

Construction : Splashproof

Weight : <100 g

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : -40°C to +85°C
Storage temperature range : -55°C to +85°C

(* Average power at 25°C per RF Path)

(** At 25° C ±10%)

(*** Nominal voltage; 25° C)



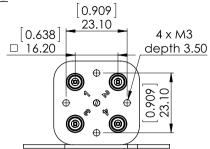


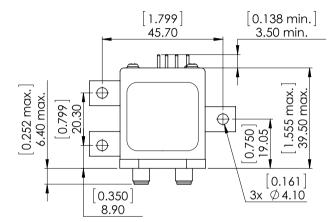


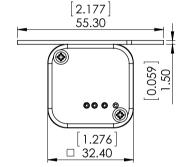
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DRAWING

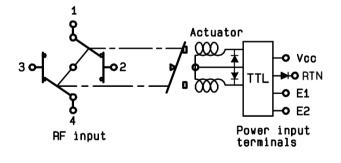






General tolerances: ±0,5 mm [0,02 in]

SCHEMATIC DIAGRAM





LABEL

E1 E2 GND VCC

RADIALL® R577832100 0 - 40 GHz Un : 12V Lot : ____

 TTL input
 RF Continuity

 E1=1 / E2=0
 $1 \leftrightarrow 3$ / $2 \leftrightarrow 4$

 E1=0 / E2=1
 $1 \leftrightarrow 2$ / $3 \leftrightarrow 4$

 E1=0 / E2=0
 Memory

 E1=1 / E2=1
 Forbidden